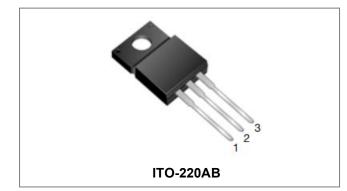


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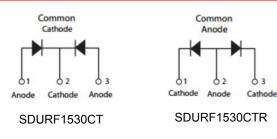
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SDURF1530CT/CTR ULTRAFAST RECTIFIER



Circuit Diagram



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	300	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=105°C, rectangular wave form	8(Per Leg) 15(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	80	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@8A, Pulse, T」= 25°C	1.01	1.3	V
	V _{F2}	@8A, Pulse, T」= 150°C	-	1.2	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_R$, $T_J = 25^{\circ}C$	0.1	10	μA
	I _{R2}	$@V_R = rated V_R$, $T_J = 125^{\circ}C$	6	500	uA
Reverse Recovery Time(Per Leg)	trr	I⊧=500mA, I _R =1A,and I _m =250mA	30	45	ns

* Pulse width < 300 µs, duty cycle < 2%

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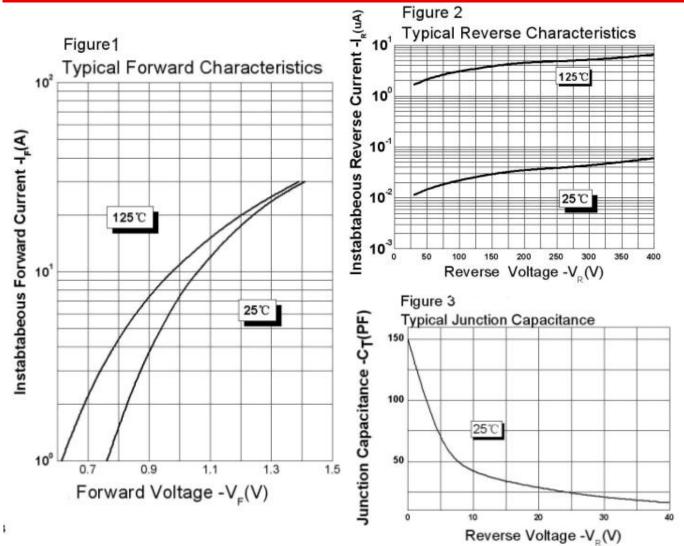
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RoHS 🗭

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			







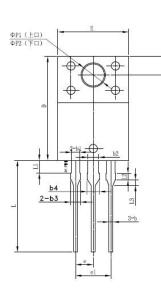
SDURF1530CT/CTR

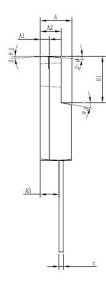
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Mechanical Dimensions ITO-220AB

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SYMBOL	Millimeters				
STMBOL	MIN.	TYP.	MAX.		
А	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
С	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦΡ1(上口)	3.30	3.50	3.70		
ΦΡ2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

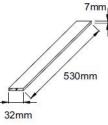
Ordering Information

Device	Package	Shipping
SDURF1530CT(CTR)	ITO-220AB (Pb-Free)	50 pcs/ tube

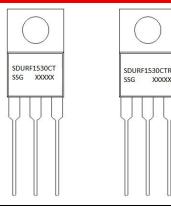
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.



Tube Specification



Marking Diagram



Where XXXXX is YYWWL

```
SDUR
          = Device Type
          = Package type
= Forward Current (15A)
F
15
30
          = Reverse Voltage (300V)
CT(CTR)
         = Configuration
SSG
           = SSG
YΥ
           = Year
WW
           = Week
           = Lot Number
L
Cautions: Molding resin
            Epoxy resin UL:94V-0
```

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SDURF1530CT/CTR



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